NSN 5961-01-247-1231

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Yes - demil/mli

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-247-1231 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.310 inches **Overall Width:** 1.050 inches **End Application:** 4935-01-108-0442 n test set **Mounting Facility Quantity:** 2 **Internal Configuration:** Field effect-dual gate Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -100.0 drain to source voltage and -100.0 drain to gate voltage **Current Rating Per Characteristic:** -19.00 amperes source cutoff current of standard range and -76.00 amperes forward current, average any acceptable **Power Rating Per Characteristic:** 125.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**